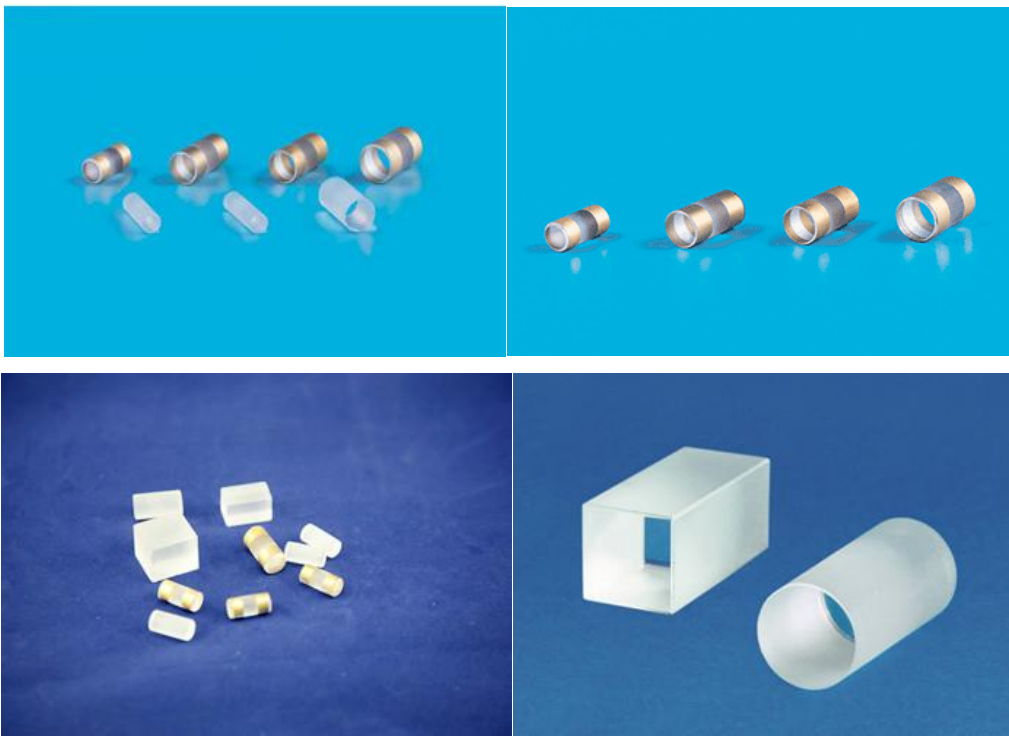


DKDP Crystals for EO applications

- Wavelength range from 0.25 μ m to 1.3 μ m
- High deuteration >98%
- Large aperture

KD*P or **DKDP crystals** are widely used in Q-switching applications at wavelength range from 0.25 μ m to approximately 1.1 μ m, If the deuterium content is higher the absorption edge of the material is shifted further into the infrared. KD*P crystal with a deuterium content >98% can be used up to 1.3 μ m. KD*P can be grown with high optical uniformity and is therefore recommended for large apertures. Hangzhou Shalom EO offers the DKDP crystals of high deuteration (>98%) for **KD*P pockels cells** applications, the customized blanks, polished crystals and the AR coating and Cr-Au electroded crystal components are available upon your request .



Modules or types

A variety types of crystals are available upon your request:

- Crystal boules with inspection polishing
- Crystal blanks with inspection polishing
- Crystals with laser grade polishing
- Crystals with AR coating and Cr-Au electrode

SPECIFICATIONS

Specification of DKDP crystals for EO applications	
Crystal materials	DKDP crystals (deuteration level >98%)
Typical diameter	6mm; 8mm; 10mm; 12mm; 15mm;
Diameter tolerance	+/-0.1mm
Length tolerance	+/-0.2mm
Surface quality	20/10 S/D
Parallelism	<20 arc seconds
Flatness	< Lambda/10 @633nm
Chamfer	0.1-0.3mmx45°
Chips	<0.15mm
Side surface	Fine ground
Orientation tolerance	< 10 arc minutes
Wavefront distortion	<Lambda/8@633nm
Extinction ratio	>2000:1
Coating	AR/AR@1064nm or customized
Damaging threshold	>800mW/cm ² @1064nm 10nS 10Hz pulse
Electrode on side surface	Chrome gold electrode (Cr+Au)
Quarter wave voltage	~3.4KV

Note: crystals with other special specification is available upon request

Basic Properties

Physical and optical properties	
Chemical Formula	KD2P
Curie temperature	222K
Symmetry	42m
Density	2.355g/cm ³
Absorption	0.005/cm
Extinction ratio	1:10000
Deuterium ratio	98.05%--99.05%
Transmission band	200-1600nm
Non-linear coefficient	d ₃₆ =0.40pm/v
Longitudinal half-wave voltage	2.98KV(I=546nm)
Electric resistance	>2x10 ⁹ Ω/cm
Electric-optical coefficient	r ₄₁ =8.8pm/v, r ₆₃ =25pm/v